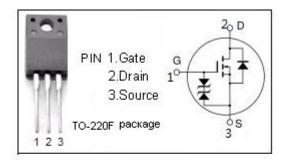


isc N-Channel MOSFET Transistor

2SK2237

DESCRIPTION

- Drain Current –I_D= 5A@ T_C=25°C
- · Drain Source Voltage-
 - : V_{DSS}= 500V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

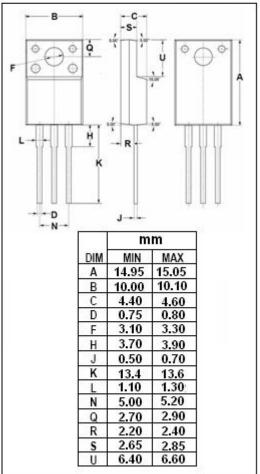


APPLICATIONS

• Switching regulators ,DC-DC converter,Motor Control



SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	500	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-continuous@ TC=25℃	5	Α
I _{D(puls)}	Pulsed Drain Current	20	Α
P _{tot}	Total Dissipation@TC=25℃	40	W
T _j	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C





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• ELECTRICAL CHARACTERISTICS (T_C=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 10mA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D =1mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.5A			1.6	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	μΑ
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500V; V _{GS} = 0			500	μΑ



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